

#### **40V NPN MEDIUM POWER HIGH GAIN TRANSISTOR IN SOT223**

#### **Features**

- $BV_{CEO} > 40V$
- I<sub>C</sub> = 5A High Continuous Collector Current
- ICM = 20A Peak Pulse Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < 120mV @ 1A
- R<sub>SAT</sub> = 50mΩ @ 5A for a Low Equivalent On-Resistance
- hFE Specified up to 10A for a High Gain Hold-Up
- Complementary PNP Type: FZT1151A
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts gualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

#### https://www.diodes.com/products/automotive/automotiveproducts/.

This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

SOT223

https://www.diodes.com/guality/product-definitions/

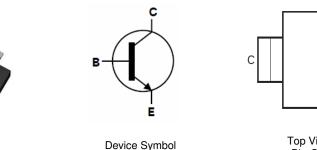
**Top View** 

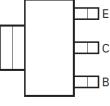
#### **Mechanical Data**

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight: 0.112 grams (Approximate)

## **Applications**

- Solenoid, Relay and Actuator Drivers
- DC Modules
- Motor Control





Top View Pin-Out

## Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FZT1051ATA	AEC-Q101	FZT1051A	7	12	1,000
FZT1051ATC	AEC-Q101	FZT1051A	13	12	4,000

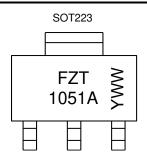
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## Marking Information

Notes:



FZT 1051A = Product Type Marking Code YWW = Date Code Marking Y or  $\overline{Y}$  = Last Digit of Year (ex: 9 = 2019) WW or  $\overline{W}W =$  Week Code (01 to 53)



## Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	150	V
Collector-Emitter Voltage	VCEO	40	V
Emitter-Base Voltage	VEBO	7	V
Continuous Collector Current	lc	5	A
Peak Pulse Current	Ісм	20	A
Base Current	IB	1	A

## Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		3.0		
Power Dissipation	(Note 6)	Pp	2.0	W	
Fower Dissipation	(Note 7)	PD	1.6	VV	
	(Note 8)		1.2		
	(Note 5)		41.7	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	D	62.5		
mermai Resistance, Junction to Ambient	(Note 7)	R <sub>0</sub> JA	78.1		
	(Note 8)		104		
Thermal Resistance Junction to Lead (Note 9)		Rejl	10.9		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

#### ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes: 5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.

7. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.

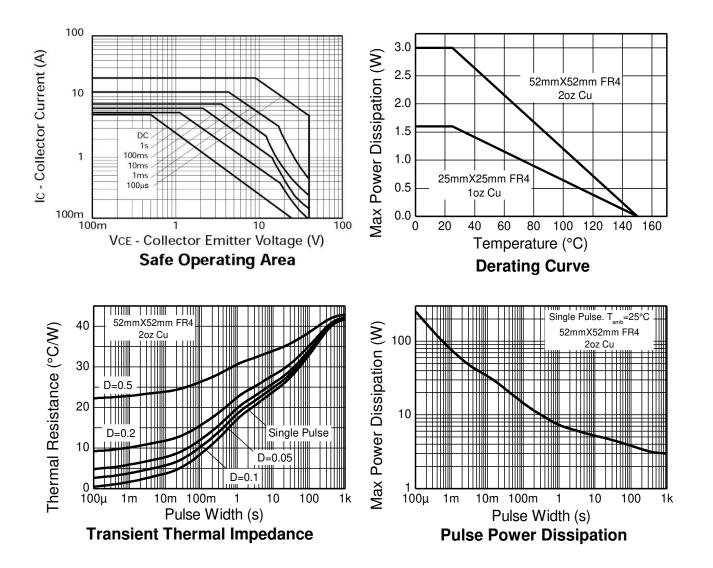
8. Same as Note 5, except the device is mounted on minimum recommended pad layout.

9. Thermal resistance from junction to solder-point (at the end of the collector lead).

10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# Thermal Characteristics and Derating Information





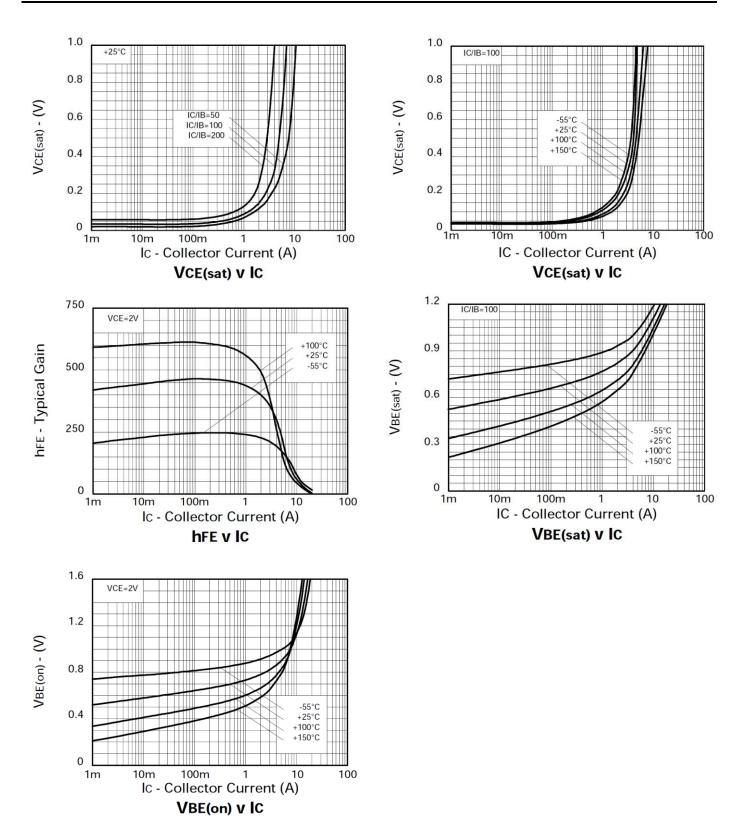
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	150	190		V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage	BVCES	150	190	_	V	$I_{c} = 100 \mu A$
Collector-Emitter Breakdown Voltage	BVCEV	150	190	_	V	$I_{C} = 100 \mu A, V_{EB} = 1V$
Collector-Emitter Breakdown Voltage (Note 11)	BVCEO	40	60	_	V	$I_{c} = 10 \text{mA}$
Emitter-Base Breakdown Voltage	BVEBO	7	8.1	_	V	I <sub>E</sub> = 100μA
Callester Ort Off Ormant	-		<1	10	nA	V <sub>CB</sub> = 120V
Collector Cut-Off Current	I <sub>CBO</sub>	—	—	0.5	μA	V <sub>CB</sub> = 120V, T <sub>A</sub> = +100°C
Collector Cut-Off Current	ICES	_	<1	10	nA	V <sub>CB</sub> = 120V
Emitter Cut-Off Current	IEBO	_	<1	10	nA	V <sub>EB</sub> = 6V
		—	17	25	mV	I <sub>C</sub> = 200mA, I <sub>B</sub> = 10mA
Collector Emiliar Columnian Valence (Nate 11)	VCE(sat)	_	85	120		$I_{C} = 1A, I_{B} = 10mA$
Collector-Emitter Saturation Voltage (Note 11)		_	140	180		$I_{C} = 2A, I_{B} = 20mA$
		—	250	340		Ic = 5A, I <sub>B</sub> = 100mA
Base-Emitter Saturation Voltage (Note 11)	VBE(sat)	_	980	1100	mV	Ic = 5A, I <sub>B</sub> = 100mA
Base-Emitter Turn-On Voltage (Note 11)	V <sub>BE(on)</sub>	_	915	1000	mV	Ic = 5A, Vce = 2V
	hfe	290	440	_		I <sub>C</sub> = 10mA, V <sub>CE</sub> = 2V
DC Current Coin (Note 11)		270	450	1200		Ic = 1A, Vce = 2V
DC Current Gain (Note 11)		130	220	_	_	$I_C = 5A, V_{CE} = 2V$
		40	55	_		I <sub>C</sub> = 10A, V <sub>CE</sub> = 2V
Output Capacitance	Cobo	—	27	40	pF	V <sub>CB</sub> = 10V, f = 1МНz
Current Gain-Bandwidth Product	f⊤	—	155	_	MHz	$V_{CE} = 10V, I_C = 50mA,$ f = 100MHz
Switching Timos	ton	_	220	_	20	$I_{C} = 3A, V_{CC} = 10V,$
Switching Times	toff	—	540	_	ns	$I_{B1} = -I_{B2} = 30mA$

Note: 11. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%



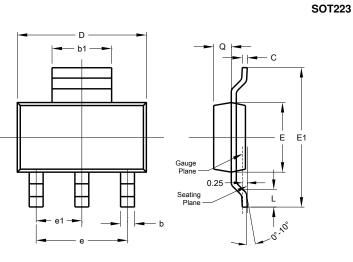
## Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

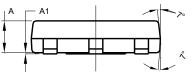




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

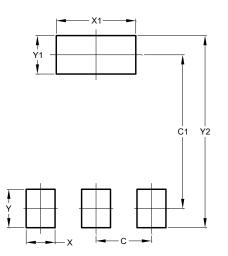




SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
E	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All [	All Dimensions in mm				

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT223

Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

# ee nup://www.aloaes.com/package



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